

Preliminary Data Sheet PD-20747 rev. A 03/01

International IR Rectifier

Hyperfast Rectifier

Features

- Hyperfast Recovery Time
- Low Forward Voltage Drop
- Low Leakage Current
- 175°C Operating Junction Temperature

$$\begin{aligned} t_{rr} &= 40\text{ns} \\ I_{F(AV)} &= 30\text{Amp} \\ V_R &= 600\text{V} \end{aligned}$$

Description/ Applications

State of the art Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, Hyperfast recover time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC Boost stage in the AC-DC section of SMPS, inverters or as freewheeling diodes.

The IR extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

Absolute Maximum Ratings

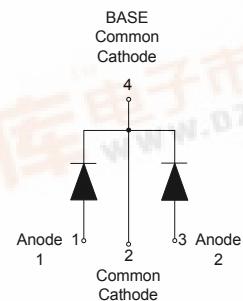
Parameters	Max	Units
V_{RRM} Peak Repetitive Peak Reverse Voltage	600	V
$I_{F(AV)}$ Average Rectified Forward Current	30	A
I_{FSM} Non Repetitive Peak Surge Current	325	
I_{FM} Peak Repetitive Forward Current	70	
T_J, T_{STG} Operating Junction and Storage Temperatures	- 65 to 175	°C

Case Styles

30CPH06



TO247AE



30CPH06

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Electrical Characteristics @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

Parameters		Min	Typ	Max	Units	Test Conditions
V_{BR}, V_r	Breakdown Voltage, Blocking Voltage	600	-	-	V	$I_R = 100\mu\text{A}$
V_F	Forward Voltage	-	-	2.3	V	$I_F = 30\text{A}, T_J = 25^\circ\text{C}$
		-	-	1.7	V	$I_F = 30\text{A}, T_J = 150^\circ\text{C}$
I_R	Reverse Leakage Current	-	-	250	μA	$V_R = V_R$ Rated
		-	-	1.0	mA	$T_J = 150^\circ\text{C}, V_R = V_R$ Rated
C_T	Junction Capacitance	-	-	-	pF	$V_R = 600\text{V}$
L_S	Series Inductance	-	-	-	nH	Measured lead to lead 5mm from package body

Dynamic Recovery Characteristics @ $T_J = 25^\circ\text{C}$ (unless otherwise specified)

Parameters		Min	Typ	Max	Units	Test Conditions
t_{rr}	Reverse Recovery Time	-	-	40	ns	$I_F = 1.0\text{A}, di_F/dt = 50\text{A}/\mu\text{s}, V_R = 30\text{V}$
		-	-	-		$I_F = 30\text{A}, di_F/dt = 200\text{A}/\mu\text{s}, V_R = 200\text{V}$
		-	-	-		$T_J = 25^\circ\text{C}$
		-	-	-		$T_J = 125^\circ\text{C}$
I_{RRM}	Peak Recovery Current	-	-	-	A	$T_J = 25^\circ\text{C}$
		-	-	-		$T_J = 125^\circ\text{C}$
Q_{rr}	Reverse Recovery Charge	-	-	100	nC	$T_J = 25^\circ\text{C}$
		-	-	-		$T_J = 125^\circ\text{C}$

Thermal - Mechanical Characteristics

Parameters		Min	Typ	Max	Units	
T_J	Max. Junction Temperature Range	-	-	-65 to 175	°C	
T_{Stg}	Max. Storage Temperature Range	-	-	-65 to 175		
R_{thJC}	Thermal Resistance, Junction to Case Per Leg	-	-	1.2	°C/W	
$R_{thJA}^{(1)}$	Thermal Resistance, Junction to Ambient Per Leg	-	-	-		
$R_{thCS}^{(2)}$	Thermal Resistance, Case to Heatsink	-	-	-		
W_t	Weight	-	2.0	-	g	
		-	0.07	-	(oz)	
Mounting Torque		6.0	-	12	Kg-cm	
		5.0	-	10	lbf.in	

(1) Typical Socket Mount

(2) Mounting Surface, Flat, Smooth and Greased